

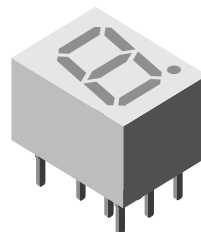
## Standard 7- Segment Display 7 mm

### Description

The TDS.11.. series are 7 mm character seven segment LED displays in a very compact package.

The displays are designed for a viewing distance up to 3 meters and available in four bright colors. The grey package surface and the evenly lighted untinted segments provide an optimum on-off contrast.

All displays are categorized in luminous intensity groups. That allows users to assemble displays with uniform appearance. Typical applications include instruments, panel meters, point-of-sale terminals and household equipment.



19235



### Features

- Evenly lighted segments
- Grey package surface
- Untinted segments
- Luminous intensity categorized
- Yellow and green categorized for color
- Wide viewing angle
- Suitable for DC and high peak current
- Lead-free device

### Applications

Panel meters  
Test- and measure- equipment  
Point-of-sale terminals  
Control units

### Parts Table

| Part     | Color, Luminous Intensity | Circuitry      |
|----------|---------------------------|----------------|
| TDSO1150 | Orange red                | Common anode   |
| TDSO1160 | Orange red                | Common cathode |
| TDSY1150 | Yellow                    | Common anode   |
| TDSG1150 | Green                     | Common anode   |
| TDSG1160 | Green                     | Common cathode |

### Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

**TDSO1150/1160, TDSY1150, TDSG1150/1160**

| Parameter                            | Test condition | Part     | Symbol | Value | Unit |
|--------------------------------------|----------------|----------|--------|-------|------|
| Reverse voltage per segment or DP    |                |          | $V_R$  | 6     | V    |
| DC forward current per segment or DP |                | TDSO1150 | $I_F$  | 17    | mA   |
|                                      |                | TDSO1160 | $I_F$  | 17    | mA   |
|                                      |                | TDSY1150 | $I_F$  | 17    | mA   |
|                                      |                | TDSG1150 | $I_F$  | 17    | mA   |
|                                      |                | TDSG1160 | $I_F$  | 17    | mA   |

| Parameter                               | Test condition                          | Part     | Symbol     | Value       | Unit       |
|-----------------------------------------|-----------------------------------------|----------|------------|-------------|------------|
| Surge forward current per segment or DP | $t_p \leq 10 \mu s$ (non repetitive)    | TDSO1150 | $I_{FSM}$  | 0.15        | A          |
|                                         |                                         | TDSO1160 | $I_{FSM}$  | 0.15        | A          |
|                                         |                                         | TDSY1150 | $I_{FSM}$  | 0.15        | A          |
|                                         |                                         | TDSG1150 | $I_{FSM}$  | 0.15        | A          |
|                                         |                                         | TDSG1160 | $I_{FSM}$  | 0.15        | A          |
| Power dissipation                       | $T_{amb} \leq 45^\circ C$               |          | $P_V$      | 400         | mW         |
| Junction temperature                    |                                         |          | $T_j$      | 100         | $^\circ C$ |
| Operating temperature range             |                                         |          | $T_{amb}$  | -40 to + 85 | $^\circ C$ |
| Storage temperature range               |                                         |          | $T_{stg}$  | -40 to + 85 | $^\circ C$ |
| Soldering temperature                   | $t \leq 3$ sec, 2mm below seating plane |          | $T_{sd}$   | 260         | $^\circ C$ |
| Thermal resistance LED junction/ambient |                                         |          | $R_{thJA}$ | 140         | K/W        |

## Optical and Electrical Characteristics

$T_{amb} = 25^\circ C$ , unless otherwise specified

### Orange red

#### TDSO1150/1160

| Parameter                                                    | Test condition   | Symbol      | Min | Typ.     | Max | Unit     |
|--------------------------------------------------------------|------------------|-------------|-----|----------|-----|----------|
| Luminous intensity per segment (digit average) <sup>1)</sup> | $I_F = 10$ mA    | $I_V$       | 450 |          |     | $\mu cd$ |
| Dominant wavelength                                          | $I_F = 10$ mA    | $\lambda_d$ | 612 |          | 625 | nm       |
| Peak wavelength                                              | $I_F = 10$ mA    | $\lambda_p$ |     | 630      |     | nm       |
| Angle of half intensity                                      | $I_F = 10$ mA    | $\phi$      |     | $\pm 50$ |     | deg      |
| Forward voltage per segment or DP                            | $I_F = 20$ mA    | $V_F$       |     | 2        | 3   | V        |
| Reverse voltage per segment or DP                            | $I_R = 10 \mu A$ | $V_R$       | 6   | 15       |     | V        |

<sup>1)</sup>  $I_{Vmin}$  and  $I_V$  groups are mean

### Yellow

#### TDSY1150

| Parameter                                                    | Test condition   | Symbol      | Min | Typ.     | Max | Unit     |
|--------------------------------------------------------------|------------------|-------------|-----|----------|-----|----------|
| Luminous intensity per segment (digit average) <sup>1)</sup> | $I_F = 10$ mA    | $I_V$       | 450 |          |     | $\mu cd$ |
| Dominant wavelength                                          | $I_F = 10$ mA    | $\lambda_d$ | 581 |          | 594 | nm       |
| Peak wavelength                                              | $I_F = 10$ mA    | $\lambda_p$ |     | 585      |     | nm       |
| Angle of half intensity                                      | $I_F = 10$ mA    | $\phi$      |     | $\pm 50$ |     | deg      |
| Forward voltage per segment or DP                            | $I_F = 20$ mA    | $V_F$       |     | 2.4      | 3   | V        |
| Reverse voltage per segment or DP                            | $I_R = 10 \mu A$ | $V_R$       | 6   | 15       |     | V        |

<sup>1)</sup>  $I_{Vmin}$  and  $I_V$  groups are mean

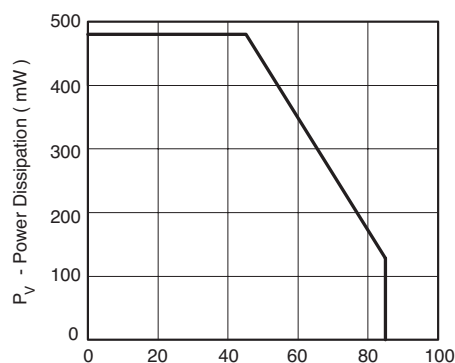
## Green

### TDSG1150/1160

| Parameter                                                    | Test condition         | Symbol      | Min | Typ.     | Max | Unit           |
|--------------------------------------------------------------|------------------------|-------------|-----|----------|-----|----------------|
| Luminous intensity per segment (digit average) <sup>1)</sup> | $I_F = 10 \text{ mA}$  | $I_V$       | 450 |          |     | $\mu\text{cd}$ |
| Dominant wavelength                                          | $I_F = 10 \text{ mA}$  | $\lambda_d$ | 562 |          | 575 | nm             |
| Peak wavelength                                              | $I_F = 10 \text{ mA}$  | $\lambda_p$ |     | 565      |     | nm             |
| Angle of half intensity                                      | $I_F = 10 \text{ mA}$  | $\varphi$   |     | $\pm 50$ |     | deg            |
| Forward voltage per segment or DP                            | $I_F = 20 \text{ mA}$  | $V_F$       |     | 2.4      | 3   | V              |
| Reverse voltage per segment or DP                            | $I_R = 10 \mu\text{A}$ | $V_R$       | 6   | 15       |     | V              |

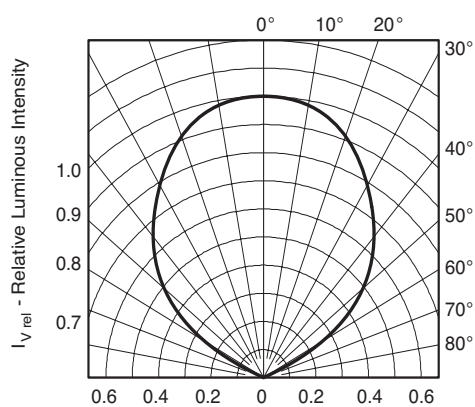
<sup>1)</sup>  $I_{V\min}$  and  $I_V$  groups are mean

### Typical Characteristics ( $T_{\text{amb}} = 25^\circ\text{C}$ unless otherwise specified)



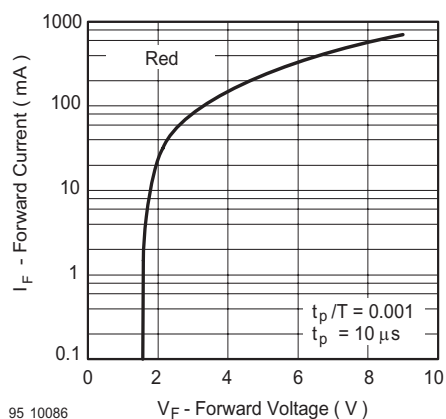
95 11479  $T_{\text{amb}}$  - Ambient Temperature ( $^\circ\text{C}$ )

Figure 1. Power Dissipation vs. Ambient Temperature



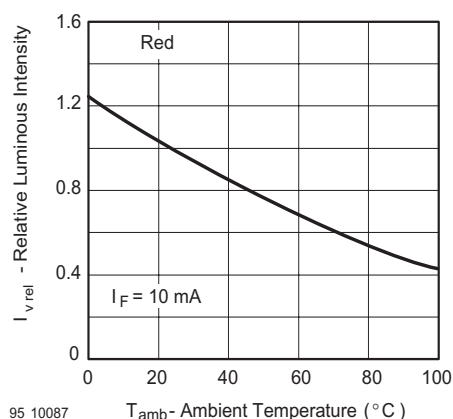
95 10082

Figure 3. Rel. Luminous Intensity vs. Angular Displacement



95 10086

Figure 2. Forward Current vs. Forward Voltage



95 10087

Figure 4. Rel. Luminous Intensity vs. Ambient Temperature

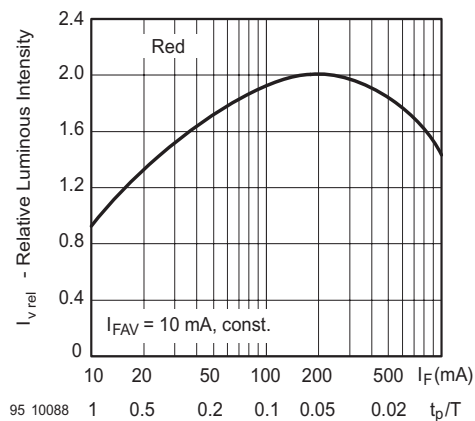


Figure 5. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

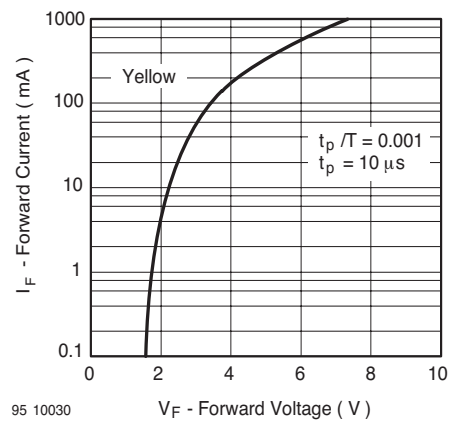


Figure 8. Forward Current vs. Forward Voltage

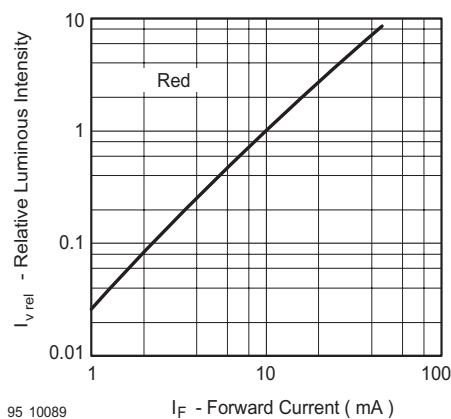


Figure 6. Relative Luminous Intensity vs. Forward Current

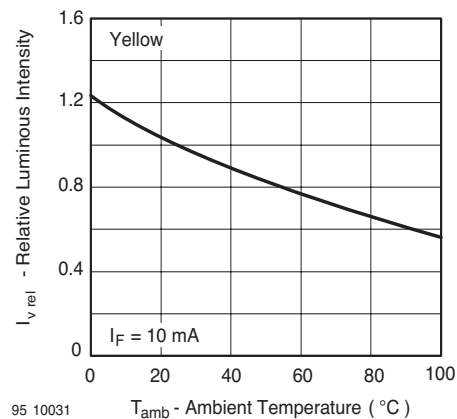


Figure 9. Rel. Luminous Intensity vs. Ambient Temperature

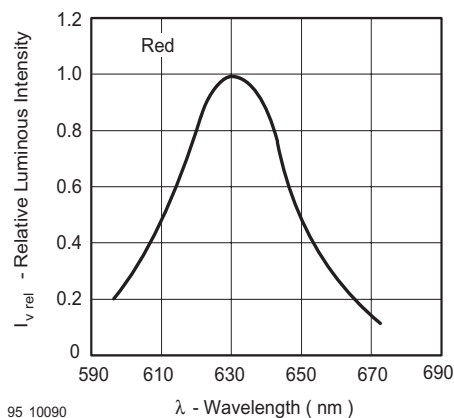


Figure 7. Relative Intensity vs. Wavelength

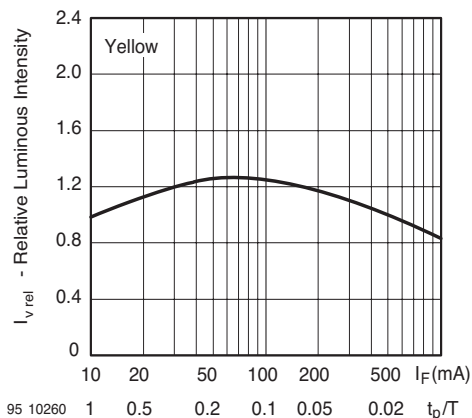


Figure 10. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

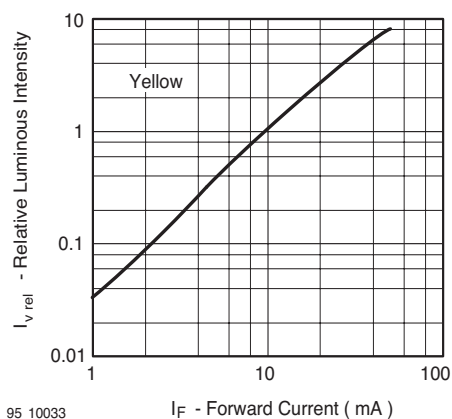


Figure 11. Relative Luminous Intensity vs. Forward Current

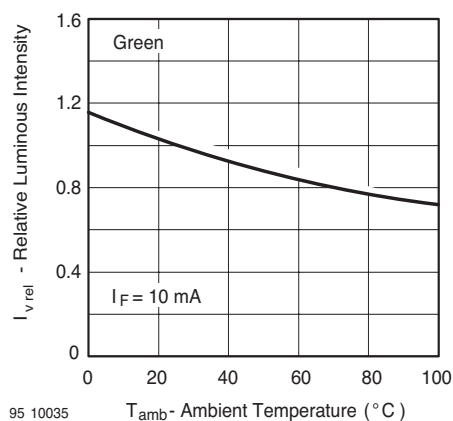


Figure 14. Rel. Luminous Intensity vs. Ambient Temperature

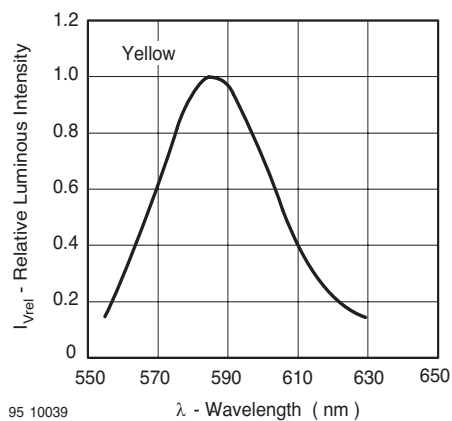


Figure 12. Relative Intensity vs. Wavelength

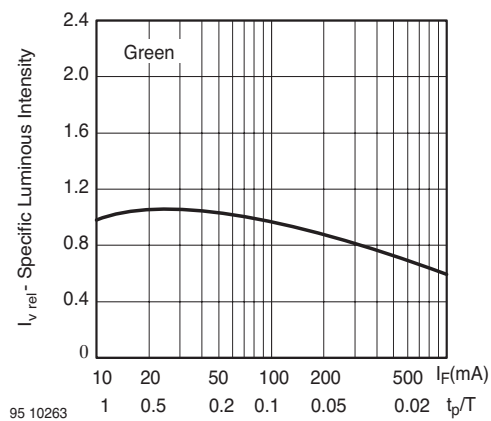


Figure 15. Specific Luminous Intensity vs. Forward Current

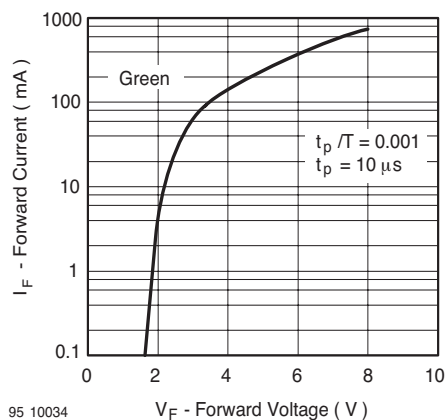


Figure 13. Forward Current vs. Forward Voltage

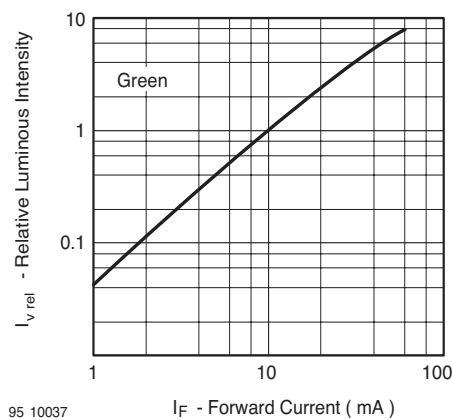


Figure 16. Relative Luminous Intensity vs. Forward Current

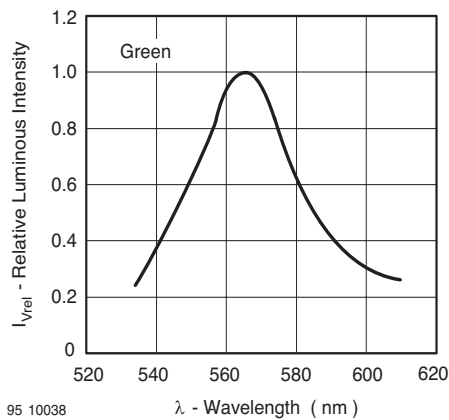
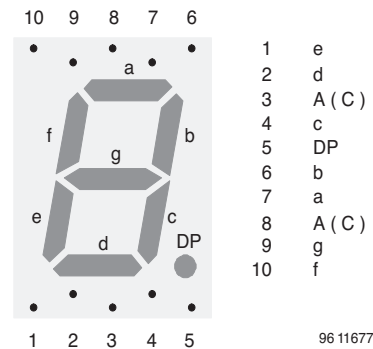
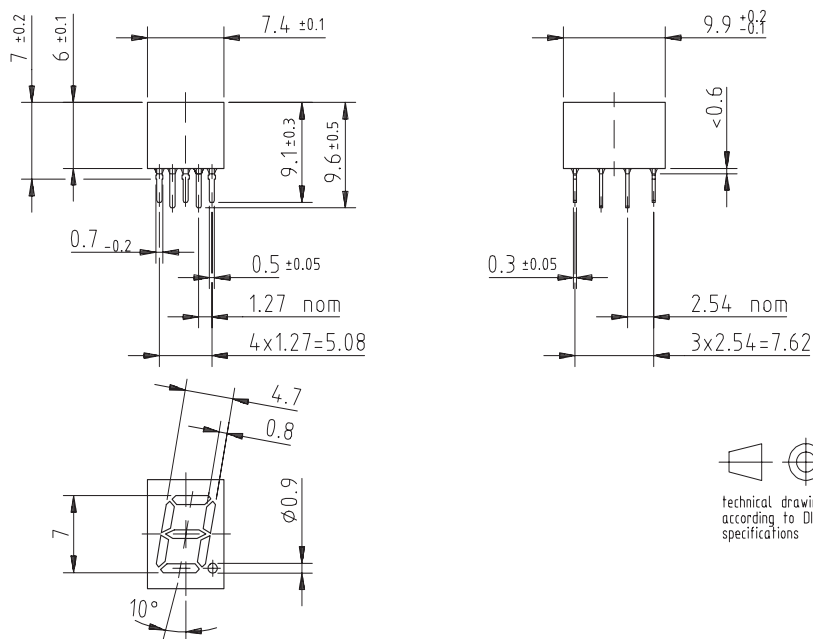


Figure 17. Relative Intensity vs. Wavelength



## Package Dimensions in mm





## **Ozone Depleting Substances Policy Statement**

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

### **We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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